

# MOS FIELD EFFECT TRANSISTOR

2SK2112

### N-CHANNEL MOS FET FOR HIGH-SPEED SWITCHING

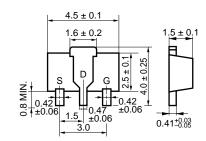
The 2SK2112 is a N-channel MOS FET of a vertical type and is a switching element that can be directly driven by the output of an IC operating at 5 V.

This product has a low ON resistance and superb switching characteristics and is ideal for driving the actuators, such as motors and DC/DC converters.

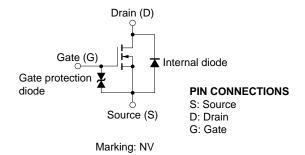
#### **FEATURES**

- Low ON resistance  $R_{DS(on)} = 1.2 \Omega$  MAX.  $@V_{GS} = 4.0 \text{ V}, \text{ ID} = 0.5 \text{ A}$
- High switching speed ton + toff < 100 ns</li>
- · Low parasitic capacitance

#### PACKAGE DIMENSIONS (in mm)



#### **EQUIVALENT CIRCUIT**



#### ABSOLUTE MAXIMUM RATINGS (TA = 25 °C)

PARAMETER	SYMBOL	TEST CONDITIONS	RATING	UNIT
Drain to Source Voltage	Voss	V <sub>G</sub> S = 0	100	V
Gate to Source Voltage	Vgss	V <sub>DS</sub> = 0	±20	V
Drain Current (DC)	I <sub>D(DC)</sub>		±1.0	Α
Drain Current (Pulse)	D(pulse)	PW ≤ 10 ms,	±2.0	А
		Duty cycle ≤ 50 %		
Total Power Dissipation	Рт	16 cm $^2 \times 0.7$ mm, ceramic substrate used	2.0	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

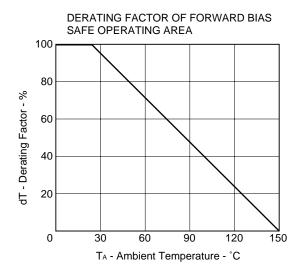


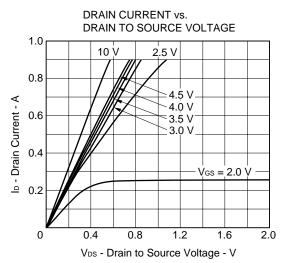
## ELECTRICAL CHARACTERISTICS (TA = 25 °C)

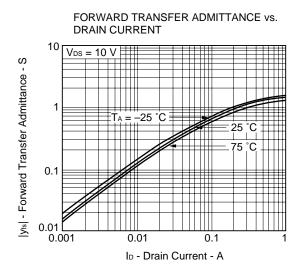
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain Cut-Off Current	Ioss	V <sub>DS</sub> = 100 V, V <sub>GS</sub> = 0			1.0	μΑ
Gate Leakage Current	Igss	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$			±10	μΑ
Gate Cut-Off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	0.8	1.5	2.0	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.5 A	0.4			S
Drain to Source On-State Resistance	RDS(on)1	Vgs = 4.0 V, ID =0.5 A		0.58	1.2	Ω
Drain to Source On-State Resistance	RDS(on)2	Vgs = 10 V, ID = 0.5 A		0.50	0.8	Ω
Input Capacitance	Ciss	V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 0, f = 1.0 MHz		178		pF
Output Capacitance	Coss			59		pF
Reverse Transfer Capacitance	Crss			16		pF
Turn-On Delay Time	td(on)	$V_{DD} = 25 \text{ V, } I_{D} = 0.5 \text{ A}$ $V_{GS(on)} = 10 \text{ V, } R_{G} = 10 \Omega$ $R_{L} = 50 \Omega$		2.9		ns
Rise Time	tr			1.7		ns
Turn-Off Delay Time	td(off)			60		ns
Fall Time	t <sub>f</sub>			15		ns

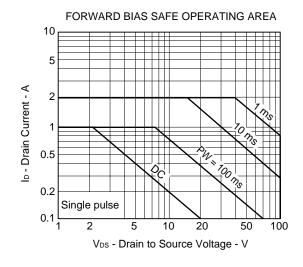
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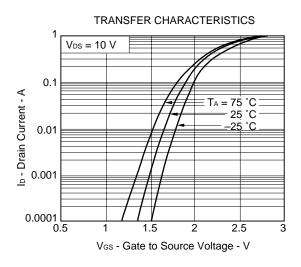
#### TYPICAL CHARACTERISTICS (TA = 25 °C)

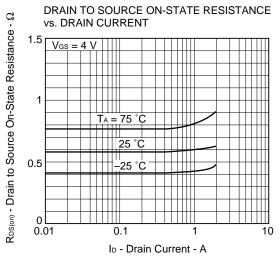




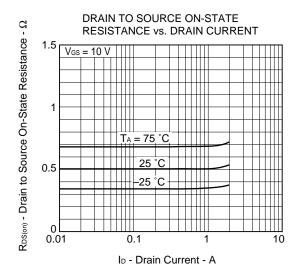


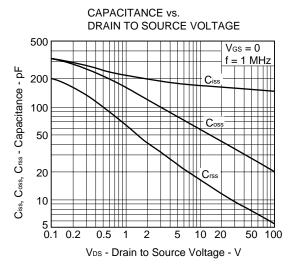


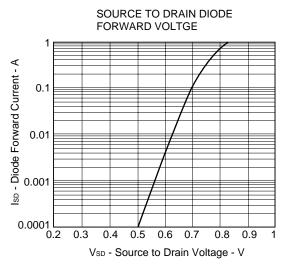


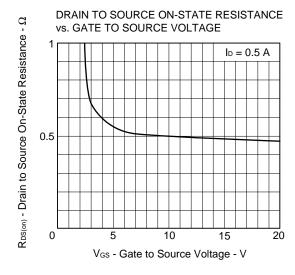


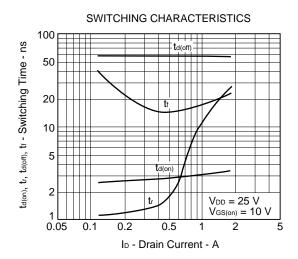














## REFERENCE

Document Name	Document No.		
NEC semiconductor device reliability/quality control system	TEI-1202		
Quality grade on NEC semiconductor devices	IEI-1209		
Semiconductor device mounting technology manual	C10535E		
Guide to quality assurance for semiconductor devices	MEI-1202		
Semiconductor selection guide	X10679E		

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Anti-radioactive design is not implemented in this product.

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